

AFGHL40T120RWD

ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
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SWITCHING CHARACTERISTICS

-		Ω	-		-	
-			-		-	
			-		-	
			-		-	
-						

AFGHL40T120RWD

TYPICAL CHARACTERISTICS



Figure 1. Output Characteristics

Figure 2. Output Characteristics

AFGHL40T120RWD

TYPICAL CHARACTERISTICS

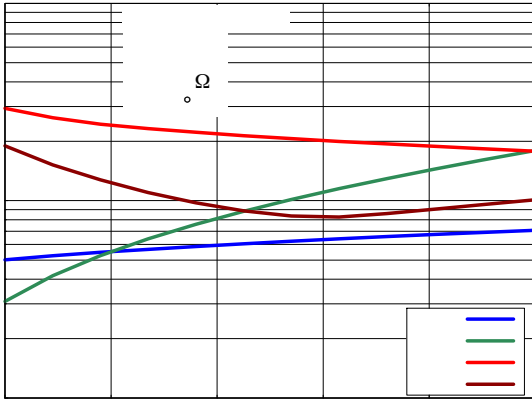


Figure 13. Switching Time vs. Collector Current

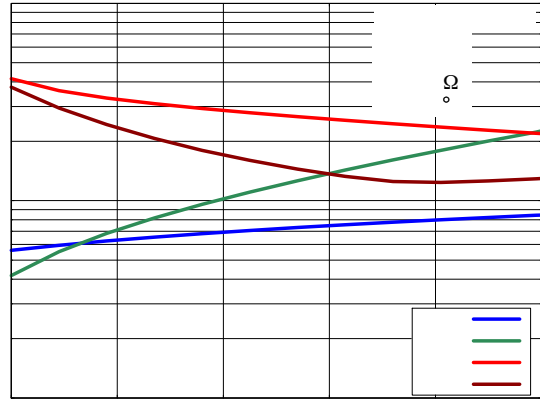


Figure 14. Switching Time vs. Collector Current

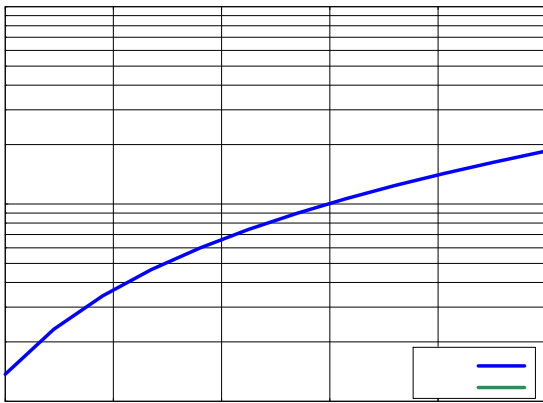


Figure 15. Switching Loss vs. Collector Current

Figure 16. Switching Loss vs. Collector Current

AFGHL40T120RWD

TYPICAL CHARACTERISTICS

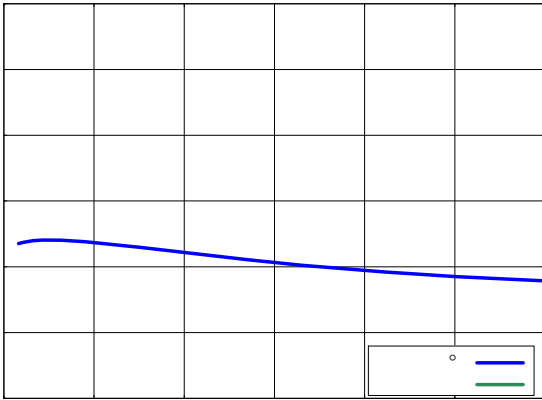


Figure 19. Diode Reverse Recovery Time

Figure 20. Diode Stored Charge Characteristics

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